



DPLS350Y

50V PNP LOW SATURATION POWER TRANSISTOR IN SOT89

Features

- BV_{CEO} > -50V
- I_C = -3A High Continuous Collector Current
- I_{CM} up to -5A Peak Pulse Current
- 2W Power Dissipation
- Low Saturation Voltage V_{CE(sat)} < -180mV @ 1A
- R_{CE(sat)} = 67mΩ @ 2A for a Low Equivalent On-Resistance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

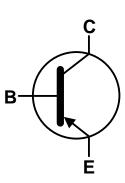
Case: SOT89

- Case Material: Molded Plastic, "Green" Molding Compound UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.052 grams (Approximate)

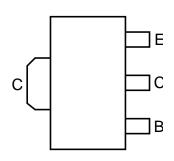
SOT89



Top View



Device Symbol



Top View Pin-Out

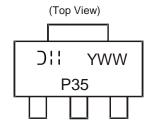
Ordering Information (Note 4)

| Part Number | Marking | Reel Size (inches) | Tape Width (mm) | Quantity per Reel |
|--------------|---------|--------------------|-----------------|-------------------|
| DPLS350Y-13 | P35 | 13 | 12 | 2,500 |
| DPLS350Y-13R | P35 | 13 | 12 | 4,000 |
| DPLS350YTC | P35 | 13 | 12 | 4,000 |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



P35 = Product Type Marking Code: YWW = Date Code Marking Y = Last Digit of Year ex: 5 = 2015 WW = Week Code 01 - 53



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | -50 | V |
| Collector-Emitter Voltage | V _{CEO} | -50 | V |
| Emitter-Base Voltage | V _{EBO} | -6 | V |
| Continuous Collector Current | Ic | -3 | Α |
| Peak Pulse Current | I _{CM} | -5 | Α |
| Base Current | I _B | -500 | mA |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit | | |
|---|-----------------------------------|-----------------|------|------|--|
| | (Note 5) | | 1 | | |
| Power Dissipation | (Note 6) | P _D | 1.6 | W | |
| | (Note 7) | | 2.0 | 1 | |
| | (Note 5) | | 125 | | |
| Thermal Resistance, Junction to Ambient Air | (Note 6) | $R_{	heta JA}$ | 78 | °C/W | |
| | (Note 7) | | 62.5 | | |
| Thermal Resistance, Junction to Lead (Note 8) | | $R_{\theta JL}$ | 5.7 | °C/W | |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C | | |

ESD Ratings (Note 9)

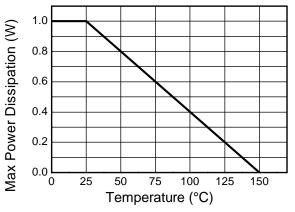
| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | 400 | V | С |

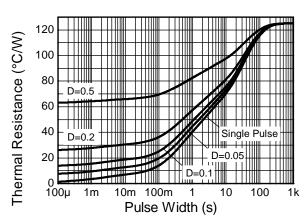
Notes:

- 5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as note (5), except the device is mounted on 25mm x 25mm 1oz copper.
- 7. Same as note (5), except the device is mounted on 50mm x 50mm 1oz copper.
- 8. Thermal resistance from junction to solder-point (on the exposed collector pad).
 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



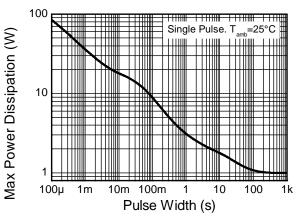
Thermal Characteristics and Derating Information



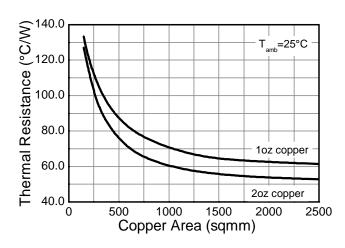


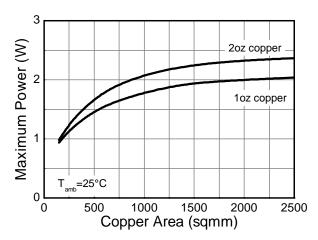
Derating Curve

Transient Thermal Impedance



Pulse Power Dissipation





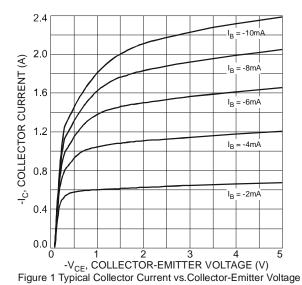


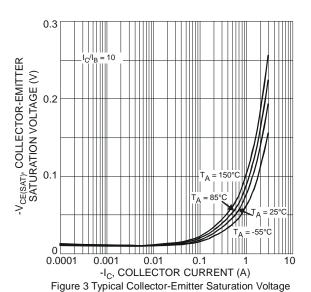
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|---|----------------------|-----|-----|------|------|--|--|
| Collector-Base Breakdown Voltage | BV _{CBO} | -50 | _ | _ | V | I _C = -100μA | |
| Collector-Emitter Breakdown Voltage (Note 10) | BV _{CEO} | -50 | _ | _ | V | I _C = -10mA | |
| Emitter-Base Breakdown Voltage | BV _{EBO} | -6 | _ | _ | V | $I_E = -100 \mu A$ | |
| Collector-Emitter Cut-off Current | I _{CES} | _ | _ | -100 | nA | V _{CE} = -50V | |
| Collector Cut-off Current | I _{CBO} | _ | 1 | -100 | nA | V _{CB} = -50V | |
| Collector Cut-on Current | | | | -50 | μA | V _{CB} = -50V, T _A = +150°C | |
| Emitter Cut-off Current | I _{EBO} | _ | _ | -100 | nA | V _{EB} = -5V | |
| | | 200 | | _ | | I _C = -100mA, V _{CE} = -2V | |
| | | 200 | | _ | | I _C = -500mA, V _{CE} = -2V | |
| Static Forward Current Transfer Ratio (Note 10) | h _{FE} | 200 | _ | 450 | _ | I _C = -1A, V _{CE} = -2V | |
| | | 130 | | _ | | I _C = -2A, V _{CE} = -2V | |
| | | 80 | | _ | | $I_C = -3A$, $V_{CE} = -2V$ | |
| | | | | -90 | mV | I _C = -500mA, I _B = -50mA | |
| | | _ | _ | -180 | | $I_C = -1A$, $I_B = -50mA$ | |
| Collector-Emitter Saturation Voltage (Note 10) | V _{CE(sat)} | | | -320 | | I _C = -2A, I _B = -100mA | |
| | | | | -270 | | $I_C = -2A$, $I_B = -200mA$ | |
| | | | | -390 | | $I_C = -3A$, $I_B = -300mA$ | |
| Equivalent On-Resistance | R _{CE(sat)} | 1 | 67 | 135 | mΩ | $I_C = -2A$, $I_B = -200mA$ | |
| Base-Emitter Saturation Voltage (Note 10) | V _{BE(sat)} | _ | _ | -1.1 | V | $I_C = -2A$, $I_B = -100mA$ | |
| Base-Emilier Saturation voltage (Note 10) | | | | -1.2 | | $I_C = -3A$, $I_B = -300mA$ | |
| Base-Emitter Turn-On Current (Note 10) | V _{BE(on)} | 1 | _ | -1.1 | V | $I_C = -1A, V_{CE} = -2V$ | |
| Transition Frequency | f⊤ | 100 | _ | - | MHz | $I_C = -100 \text{mA}, V_{CE} = -5 \text{V},$ f = 100 MHz | |
| Collector Output Capacitance | C _{obo} | _ | _ | 35 | pF | V _{CB} = -10V, I _E = 0, f = 1MHz | |
| Turn-On Time | t _(ON) | _ | 87 | _ | ns | | |
| Delay Time | t _D | _ | 41 | _ | ns | | |
| Rise Time | t _R | _ | 46 | _ | ns | $V_{CC} = -30v$, | |
| Turn-Off Time | t _(OFF) | _ | 294 | _ | ns | $I_{CC} = 150 \text{mA}$ $I_{B1} = I_{B2} = 15 \text{mA}$ | |
| Storage Time | ts | _ | 250 | _ | ns | - 182 = 13111A | |
| Fall Time | t _F | _ | 44 | _ | ns | | |

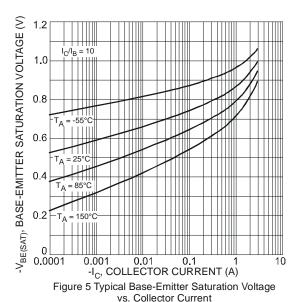
Note: 10. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

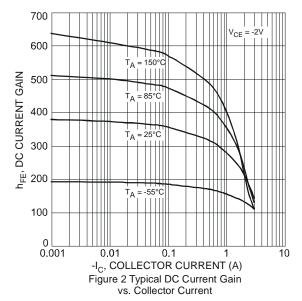


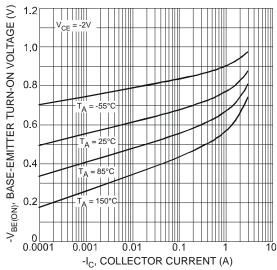




vs. Collector Current







-I_C, COLLECTOR CURRENT (A)
Figure 4 Typical Base-Emitter Turn-On Voltage
vs. Collector Current

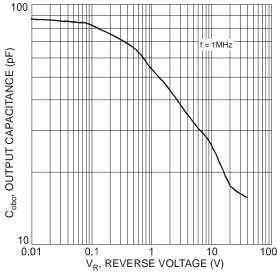
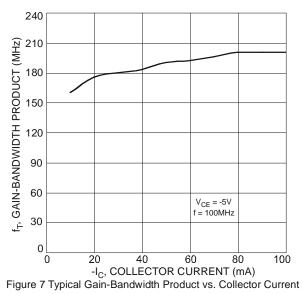


Figure 6 Typical Output Capacitance Characteristics



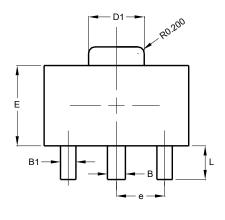


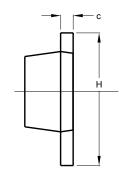


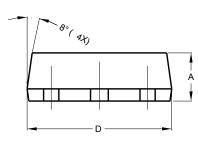
Package Outline Dimensions

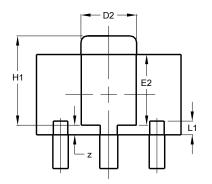
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

SOT89







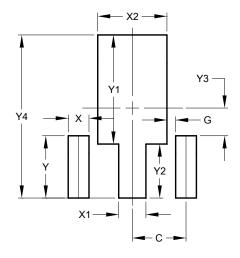


| SOT89 | | | | | |
|----------------------|-------|-------|-------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 1.40 | 1.60 | 1.50 | | |
| В | 0.50 | 0.62 | 0.56 | | |
| B1 | 0.42 | 0.54 | 0.48 | | |
| С | 0.35 | 0.43 | 0.38 | | |
| D | 4.40 | 4.60 | 4.50 | | |
| D1 | 1.62 | 1.83 | 1.733 | | |
| D2 | 1.61 | 1.81 | 1.71 | | |
| Е | 2.40 | 2.60 | 2.50 | | |
| E2 | 2.05 | 2.35 | 2.20 | | |
| е | - | - | 1.50 | | |
| Н | 3.95 | 4.25 | 4.10 | | |
| H1 | 2.63 | 2.93 | 2.78 | | |
| L | 0.90 | 1.20 | 1.05 | | |
| L1 | 0.327 | 0.527 | 0.427 | | |
| Z | 0.20 | 0.40 | 0.30 | | |
| All Dimensions in mm | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

SOT89



| Dimensions | Value (in mm) | | |
|------------|------------------|--|--|
| С | 1.500 | | |
| G | 0.244 | | |
| Х | 0.580 | | |
| X1 | 0.760 | | |
| X2 | 1.933 | | |
| Y | 1.730 | | |
| Y1 | 3.030 | | |
| Y2 | 1.500 | | |
| Y3 | 0.770 | | |
| Y4 | 4.530 | | |



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